



# Simulation of Photoluminescence Spectra

Speaker: Yu Jin

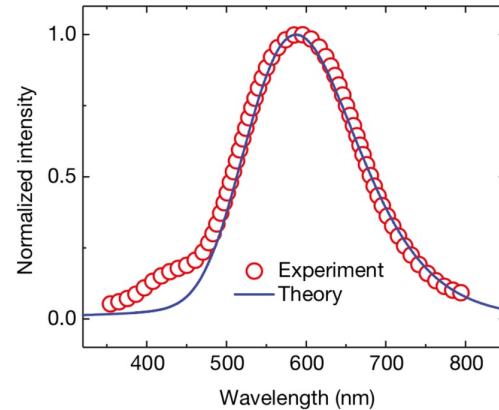
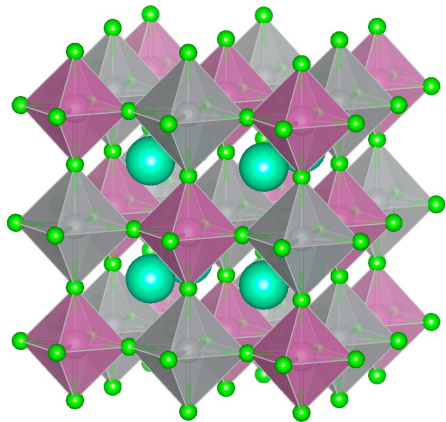
MICCoM Workshop

10/14/2022

# Introduction

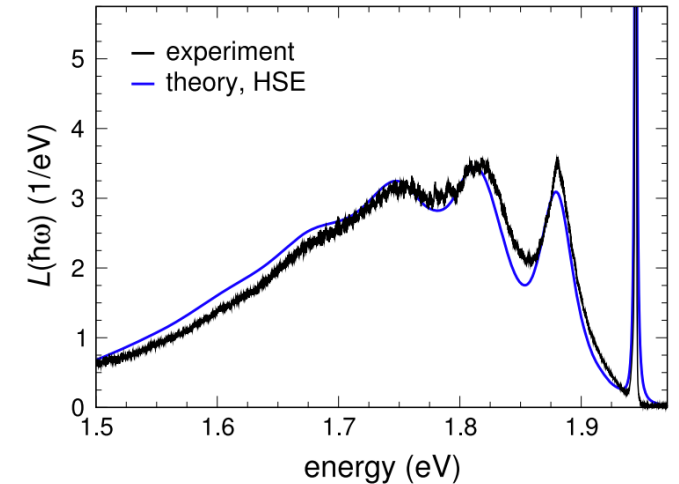
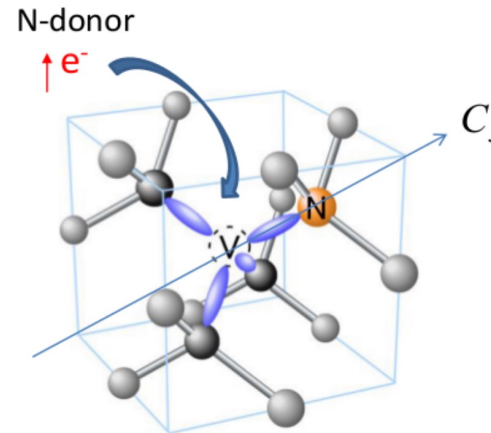
Motivation: Materials characterization requires the ability to simulate **photoluminescence (PL) spectra**

## Light emitting all inorganic perovskites



e.g., All inorganic perovskite  $\text{Cs}_2\text{AgInCl}_6$   
J. Luo et al., *Nature*. **563**, 541 (2018).

## Defect systems for quantum information science



e.g.,  $\text{NV}^-$  center in diamond  
A. Alkauskas et al., *New J. Phys.* **24**, 073026 (2014).

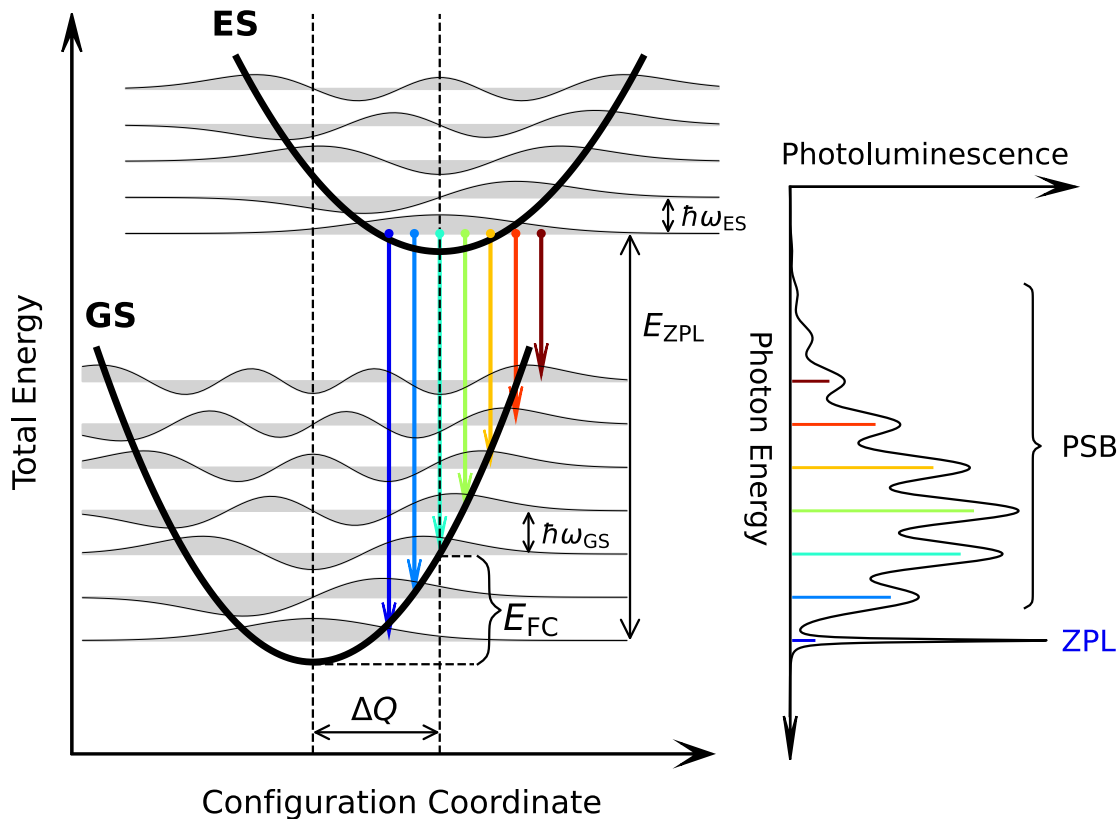
Main focus: first-principles strategies to study PL spectra of large solid-state systems

# Outline

---

- Theory and First-principles Methodology
- Photoluminescence of All Inorganic Perovskites
- Photoluminescence of Point Defects in Semiconductors
- Summary and Outlook

# Physical Processes and Approximations



- Fermi's golden rule

$$I(\hbar\omega, T) \propto \sum_{m,n} P_m(T) |\langle \Phi_m | \hat{V} | \Phi_n \rangle|^2 \delta(\hbar\omega + E_m - E_n)$$

- Electric-dipole approximation, Born-Oppenheimer approximation, Franck-Condon (FC) approximation

$$I(\hbar\omega, T) \propto |\mu_{ES,GS}|^2 \sum_{m,n} P_m(T) |\langle X_{ES,m} | X_{GS,n} \rangle|^2 \times \delta(\hbar\omega + E_{GS,n} - E_{ES,m} - E_{ZPL})$$

Nuclear wavefunction  
Zero-phonon line (ZPL)

- Franck-Condon (FC) shift:  $E_{FC} \approx \frac{1}{2} \omega^2 \Delta Q^2$
- Huang-Rhys factor (HRF):  $S = \frac{E_{FC}}{\hbar\omega} = \frac{\omega \Delta Q^2}{2\hbar}$

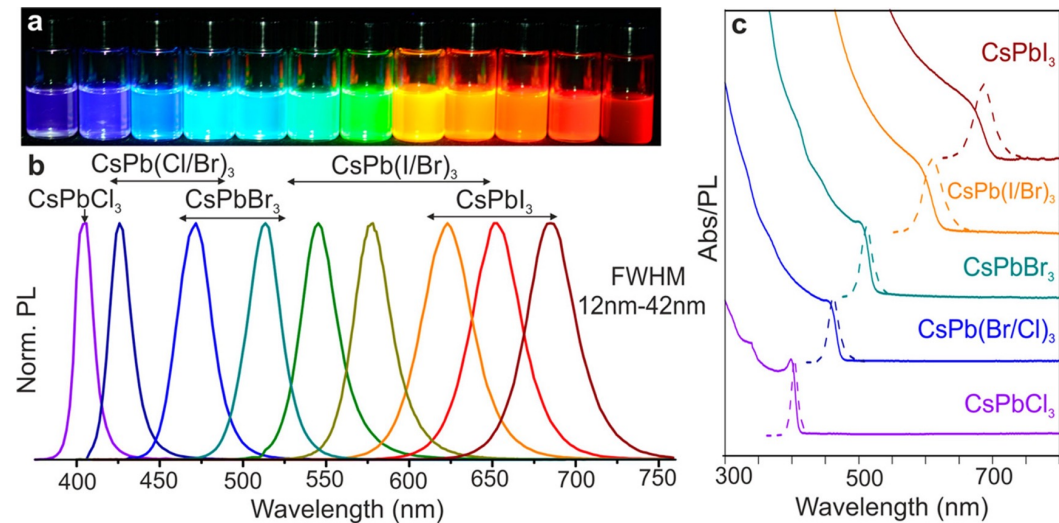
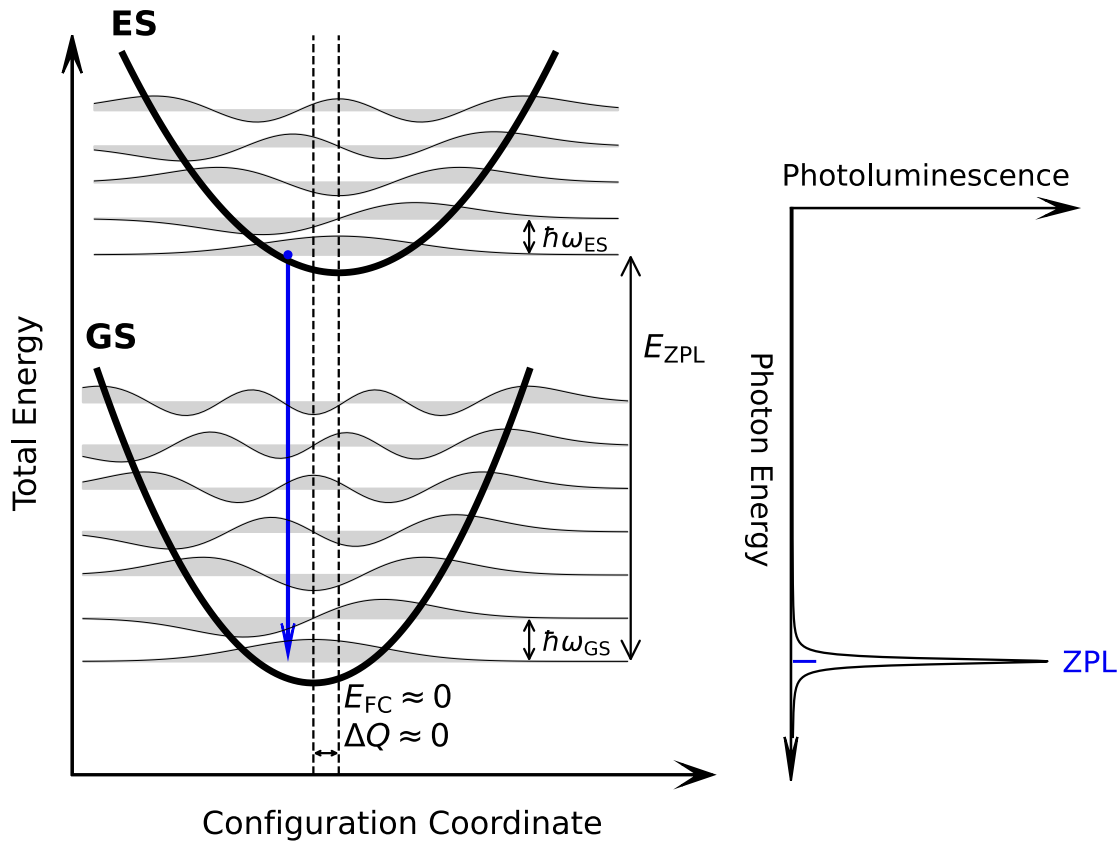
# PL with Weak Electron-Phonon (EI-Ph) Coupling

Weak electron-phonon coupling:  $S \approx 0$

Example systems: pristine solids with delocalized excitons

$$I(\hbar\omega, T) \propto |\mu_{ES,GS}|^2 \delta(\hbar\omega - E_{ZPL})$$

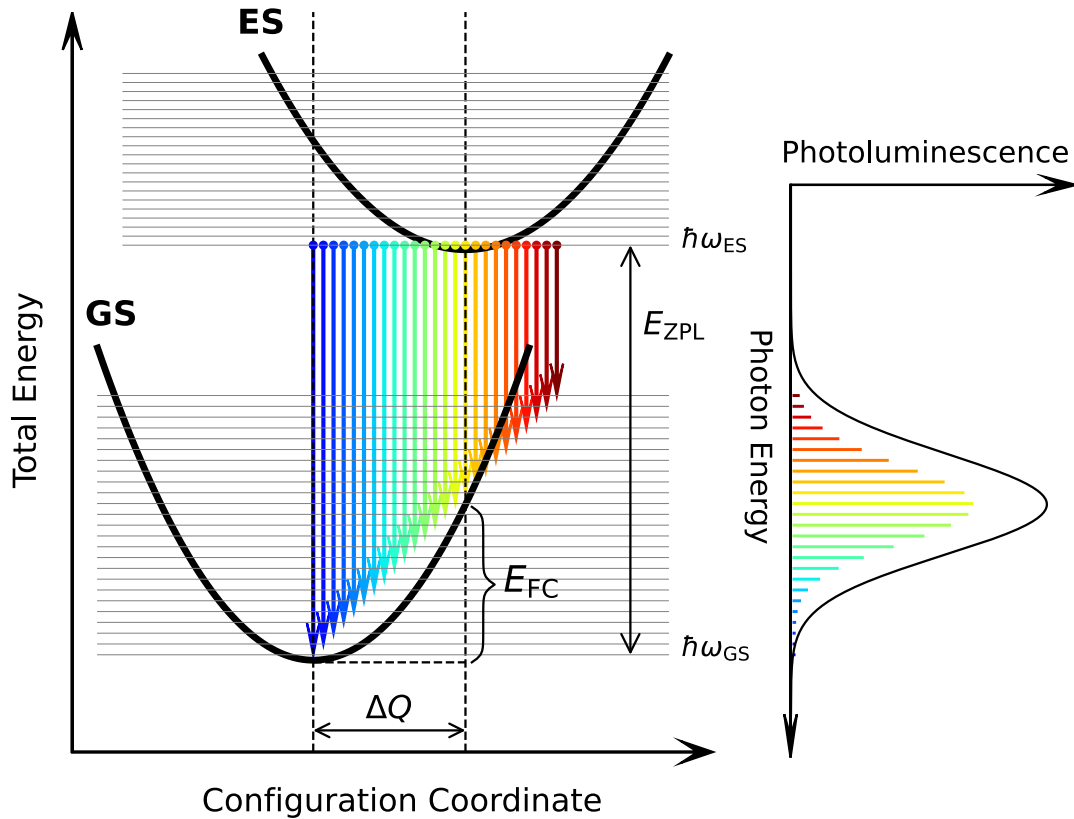
- Narrow PL line shape
- Same peak position for absorption and PL



L. Protesescu et al., *Nano Lett.* **15**, 3692 (2015).

# PL with Strong EI-Ph Coupling

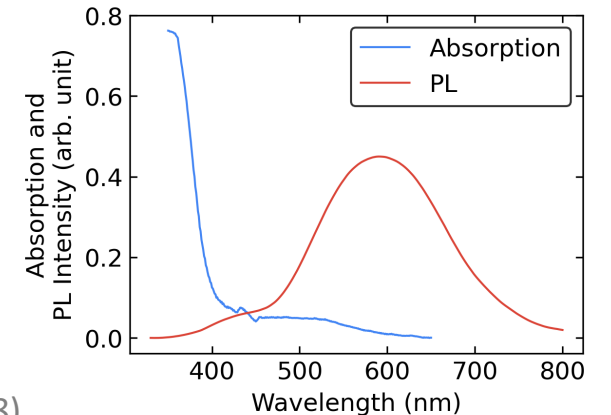
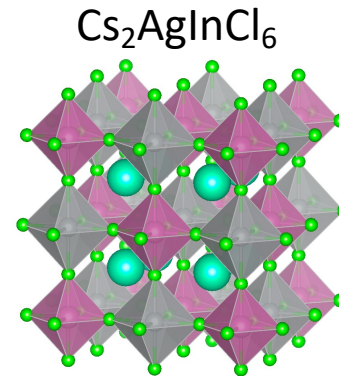
Strong electron-phonon coupling:  $S \gg 1$



$$I(\hbar\omega, T) \propto |\mu_{ES,GS}|^2 \sum_{m,n} P_m(T) |\langle X_{ES,m} | X_{GS,n} \rangle|^2 \times \delta(\hbar\omega + E_{GS,n} - E_{ES,m} - E_{ZPL})$$

Example systems: defects and self-trapped excitons in “soft” solids

- Broad PL line shape
- Different peak positions for absorption and emission

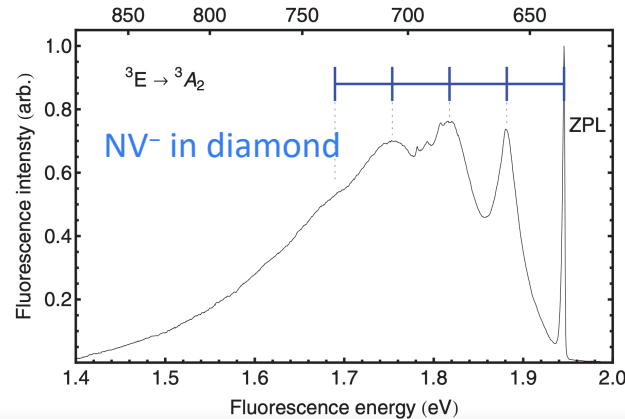


J. Luo et al., *Nature* **563**, 541 (2018).

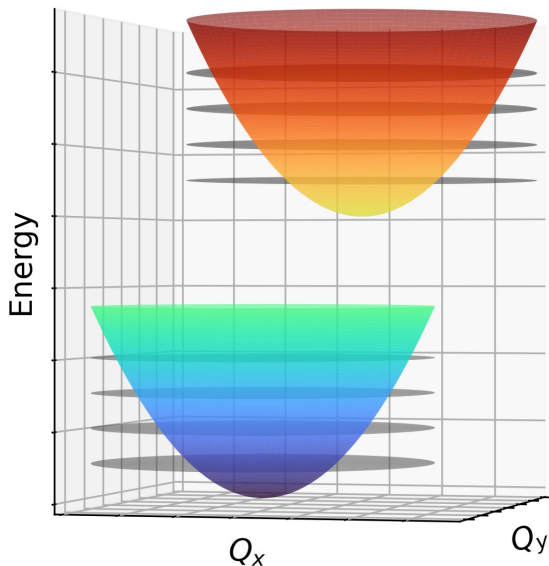


# PL with Intermediate EI-Ph Coupling

Intermediate electron-phonon coupling:  $S \approx 1$



P. Kehayas et al., *Phys. Rev. B* **88**, 165202 (2013).



$$I(\hbar\omega, T) \propto |\mu_{ES,GS}|^2 \sum_{m,n} P_m(T) |\langle X_{ES,m} | X_{GS,n} \rangle|^2 \times \delta(\hbar\omega + E_{GS,n} - E_{ES,m} - E_{ZPL})$$

Example systems: point defects in “rigid” solids

- **Multidimensional** nuclear wavefunction in  $|X_{ES,\{m\}}\rangle = \prod_k |\chi_{ES,km_k}\rangle$ ,  $|X_{GS,\{n\}}\rangle = \prod_k |\chi_{GS,kn_k}\rangle$
- **Displaced harmonic oscillator approximation**

$$\hbar\omega_{ES,k} = \hbar\omega_{GS,k}$$

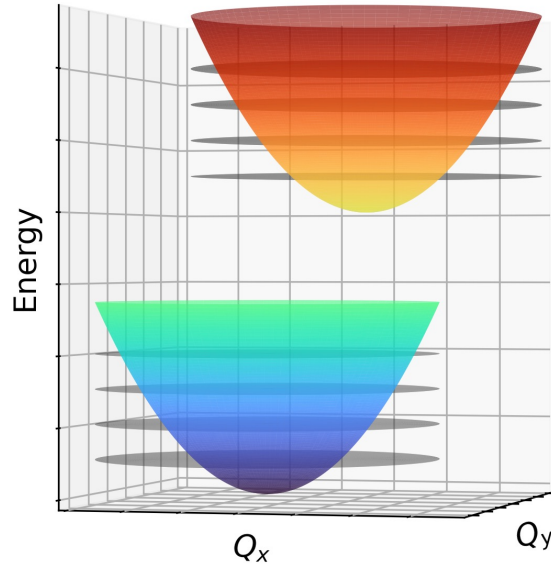
$$|\langle \chi_{k0}(Q_k - \Delta Q_k) | \chi_{kn}(Q) \rangle|^2 = \frac{S_k^n}{n!} \exp(-S_k)$$

- Partial Huang-Rhys factor (HRF):  $S_k = \frac{\omega_k \Delta Q_k^2}{2\hbar}$



# PL with Intermediate EI-Ph Coupling

## Generating function approach for PL line shape



$$I(\hbar\omega) \propto \frac{1}{2\pi\hbar} \int_{-\infty}^{\infty} \exp\left(i\omega t - \frac{iE_{\text{ZPL}}t + \lambda|t|}{\hbar}\right) G(t) dt$$

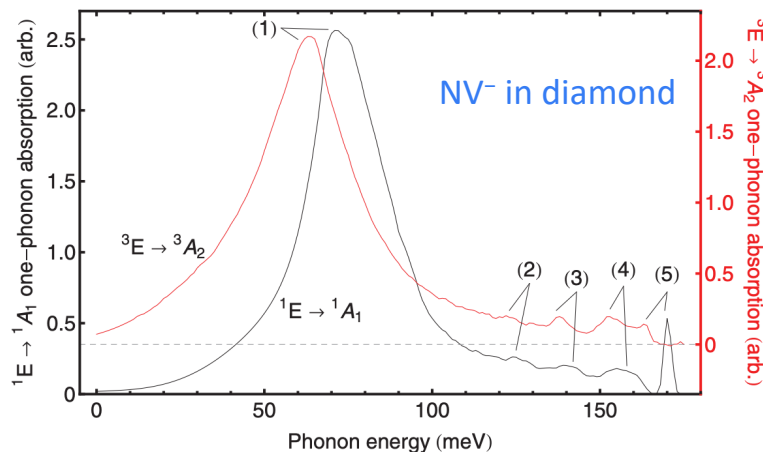
Energy of the zero-phonon line (ZPL) ↑  
Broadening of the ZPL ↓

- Generating function

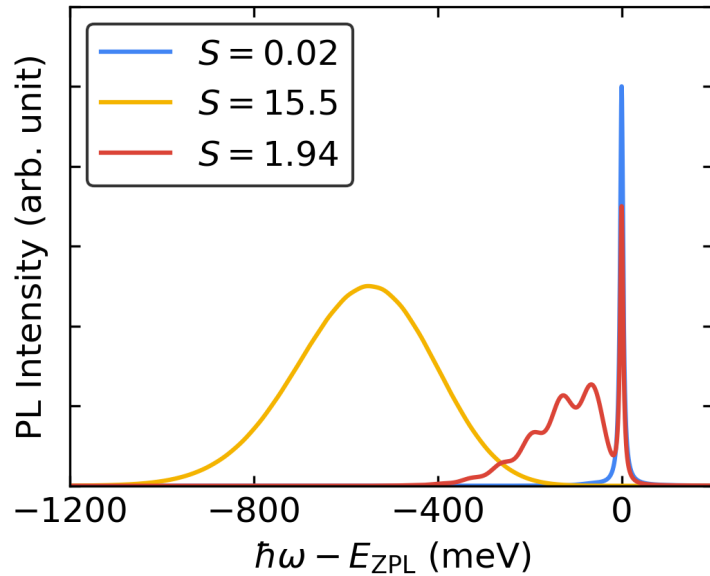
$$G(t) = \exp[S(t) - S(0)]$$

- Spectral density of electron-phonon (el-ph) coupling

$$S(\hbar\omega) = \sum_k S_k \delta(\hbar\omega - \hbar\omega_k)$$



# PL in Different EI-Ph Coupling Regimes



Coupling regimes

Weak coupling:  
 $S \approx 0$

Strong coupling:  
 $S \gg 1$

Intermediate coupling:  
 $S \approx 1$

Features

Narrow PL  
 $E_{abs} \approx E_{emi}$

Broad PL  
 $E_{abs} - E_{emi} \approx 2S\hbar\omega_{eff}$

Zero-phonon line & phonon side band

Computation

Gaussian or Lorentzian peak at  $E_{emi}$

1D CCD, effective modes, FC integrals

All modes, generating function

Example systems

Pristine solids with delocalized exciton

Self-trapped exciton in perovskites

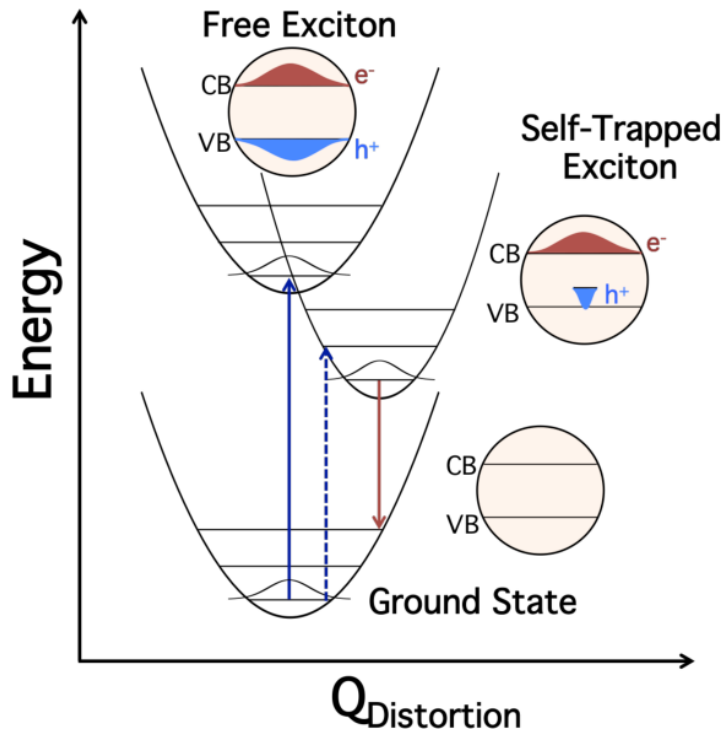
Point defects in semiconductors

# Outline

---

- Theory and First-principles Methodology
- **Photoluminescence of All Inorganic Perovskites**
- Photoluminescence of Point Defects in Semiconductors
- Summary and Outlook

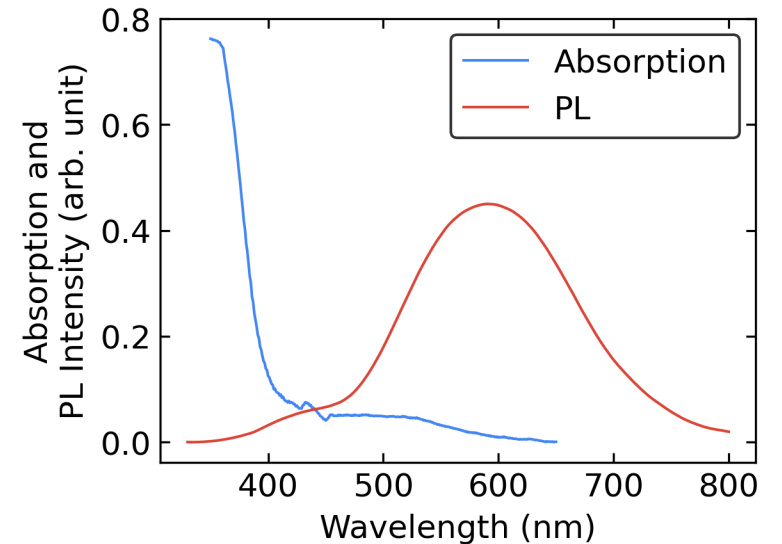
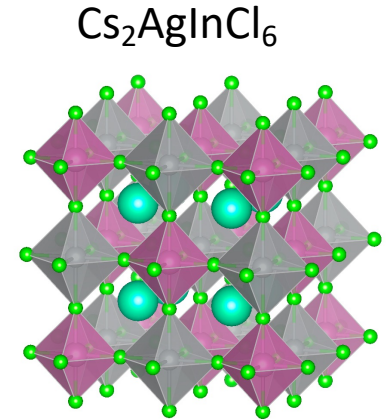
# Self trapped exciton and broadband PL



After absorbing the light free exciton is relaxed (stabilized) into a **self trapped exciton (STE)**

Systems with STE exhibit **broadband PL** and large Franck-Condon shifts

Potential application: lead-free white light source



J. Luo et al., *Nature* **563**, 541 (2018).

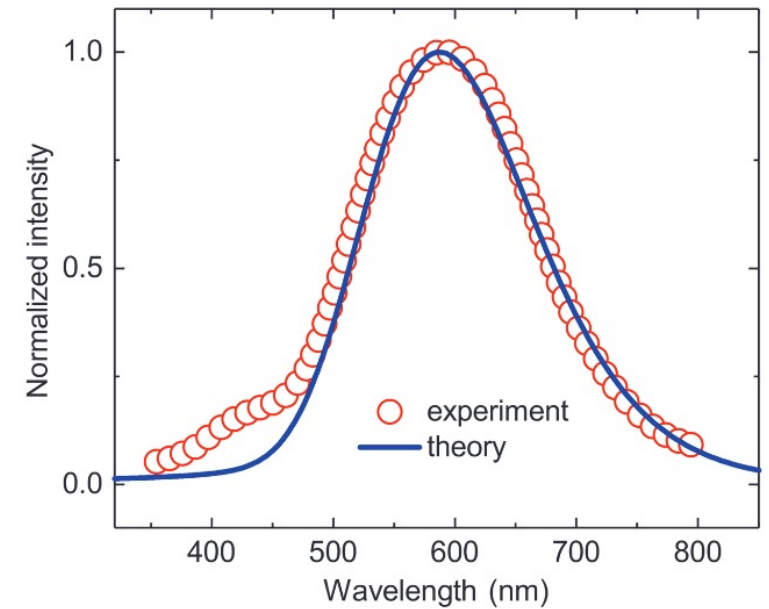
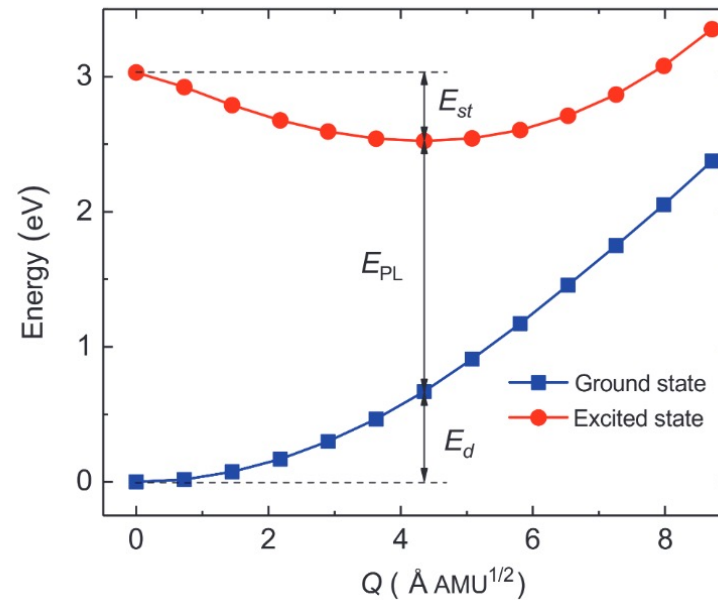
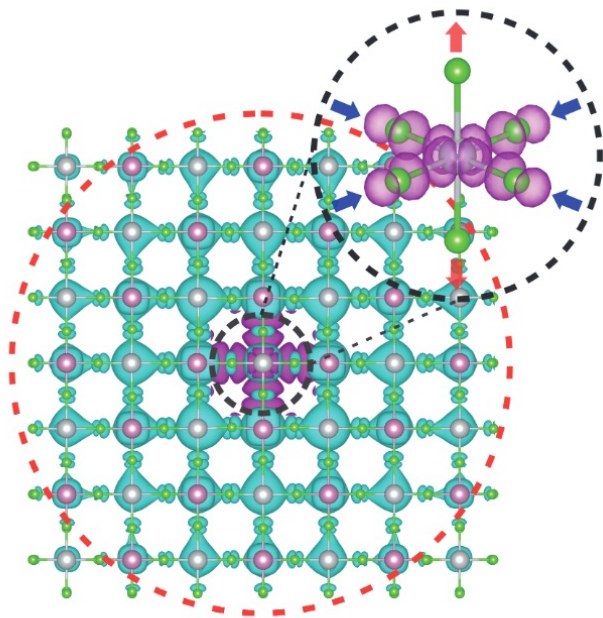
K. E. Knowles et al., *J. Am. Chem. Soc.* **137**, 13138 (2015).



# 1D CCD and the Broadband PL

The broad PL from the **self-trapped exciton** originates from the **strong electron-phonon coupling**

$\Delta Q$ (amu <sup>0.5</sup> Å)	$\hbar\omega_{GS}$ (meV)	$\hbar\omega_{ES}$ (meV)	$S_{GS}$	$S_{ES}$
4.35	18.3	17.4	37	30



J. Luo et al., *Nature* **563**, 541 (2018).

X. Wang et al., *J. Phys. Chem. Lett.* **10**, 501 (2019).

# Outline

---

- Theory and First-principles Methodology
- Photoluminescence of All Inorganic Perovskites
- **Photoluminescence of Point Defects in Semiconductors**
- Summary and Outlook

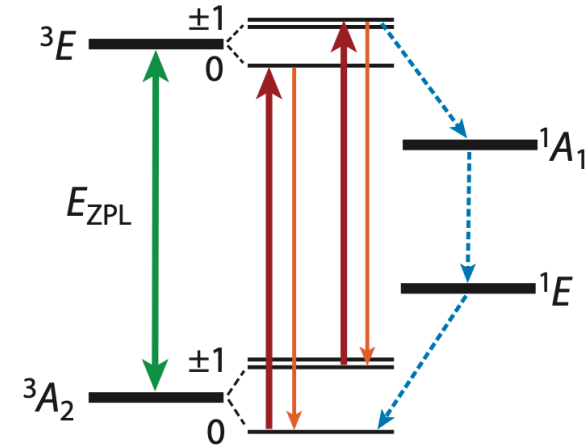
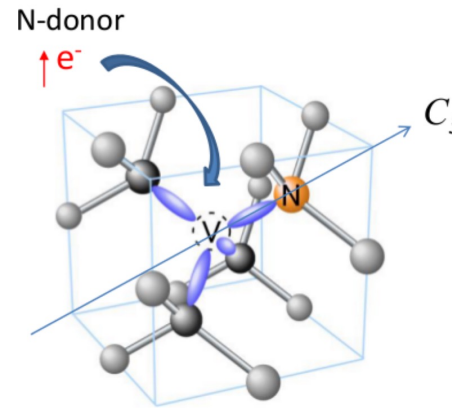
# PL of Point Defects in Semiconductors

Optically active point defects in semiconductors are potential platforms for quantum technology applications

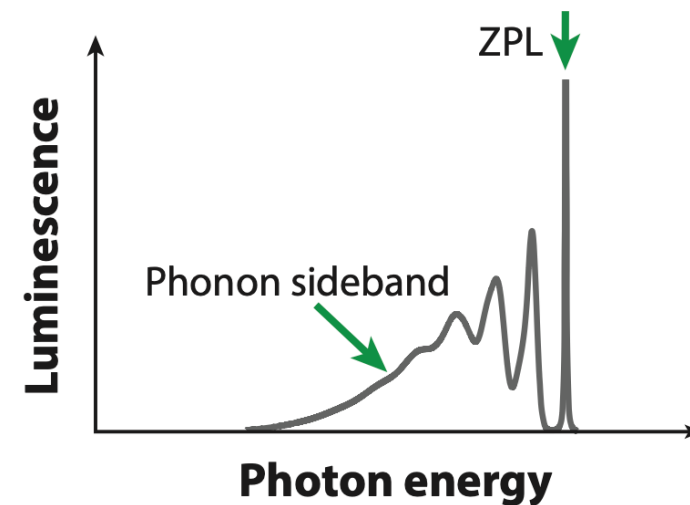
Nitrogen-vacancy ( $NV^-$ ) center in diamond

A. Gali, *Nanophotonics* **8**, 1907 (2019).

C. E. Dreyer et al., *Annu. Rev. Mater. Res.* **48**, 1 (2018).



- Characterization
- Design of spin qubits

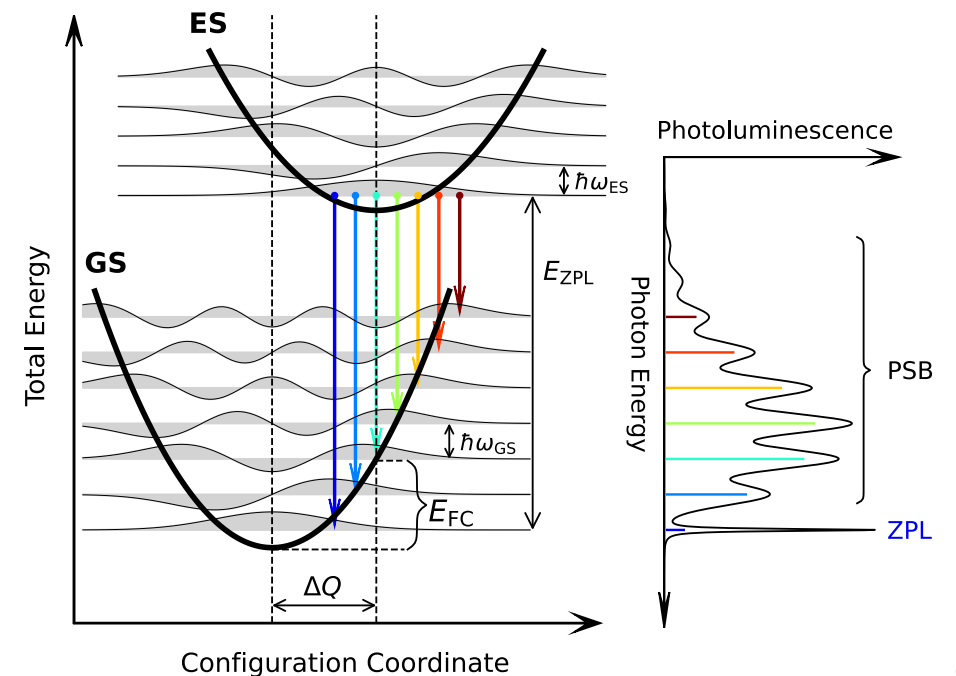
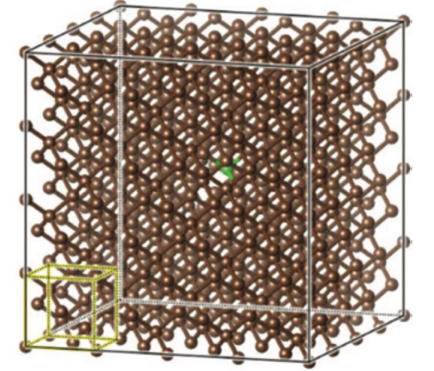




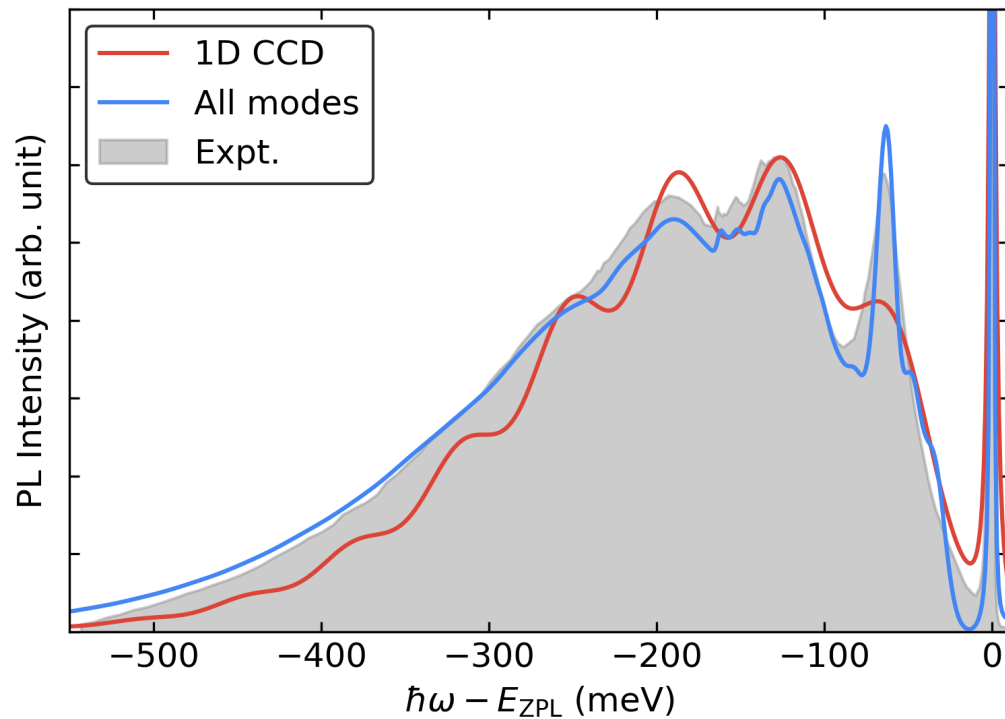
# First-principles Calculations

1. Build the structural model for the defect
  - supercell with periodic boundary condition
2. DFT study of the ground state (GS)
  - **GS atomic geometry**
  - **All phonon modes**
3. CDFT ( $\Delta$ SCF) or TDDFT study of the excited state (ES)
  - **ES atomic geometry**
  - Energy of the **zero-phonon line:  $E_{ZPL}$**
4. Compute PL using the **generating function approach**

NV<sup>-</sup> center in a (4 × 4 × 4) supercell of diamond with 512 atomic sites



# PL Line Shape of NV<sup>-</sup> in Diamond



- 1D CCD can't capture the details of the PL line shape
- The PL line shape predicted using all vibrational modes are in better agreement with the experiment
- **Finite size effects**
  - Underestimate of intensity at around -20 meV
  - Shoulder peaks around -50 meV

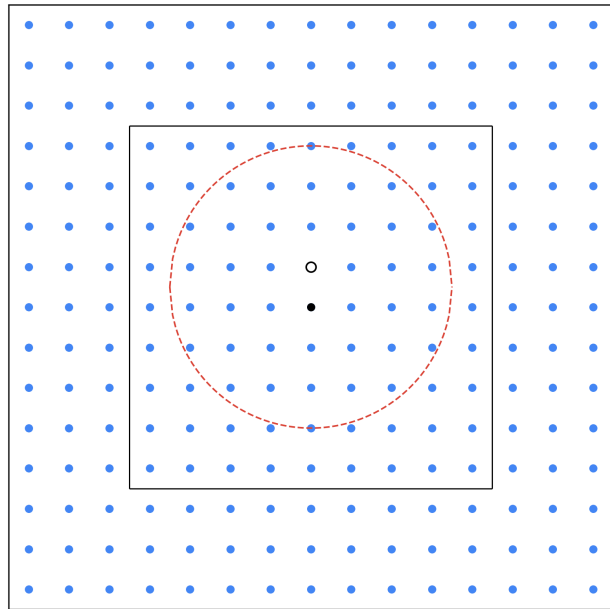
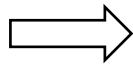
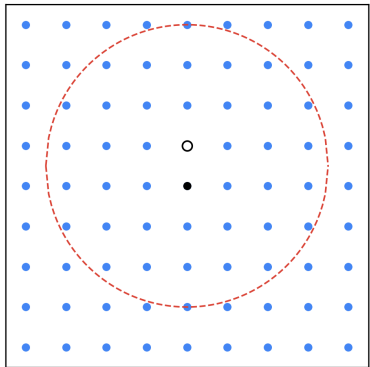
# Extrapolating to the Dilute Limit

$$\Delta Q_k = \frac{1}{\omega_k^2} \sum_{\alpha=1}^N \sum_{i=x,y,z} \frac{\mathbf{F}_{\alpha i}}{\sqrt{M_{\alpha}}} \mathbf{e}_{k,\alpha i}$$

Atomic forces ( $\mathbf{F}_{\alpha i}$ ) outside the **sphere** are negligible

( $N \times N \times N$ ) supercell

( $4 \times 4 \times 4$ ) supercell



## Force constant matrix ( $\mathbf{D}$ ) embedding approach

- If both atoms are within the **sphere**, then the matrix element of the small defect supercell is used
- If two atoms are separated by a distance larger than a chosen cutoff radius, then the matrix element is set to zero
- For all other atom pairs, the values of the pristine bulk system is used

$\mathbf{D}$  (defect in small supercell)    $\mathbf{D}$  (pristine bulk supercell)



$\mathbf{D}$  (defect in large supercell)

$$\mathbf{D} \mathbf{e}_k = \omega_k^2 \mathbf{e}$$

# Spectral Density of EI-Ph Coupling

Total Huang-Rhys factor (HRF)

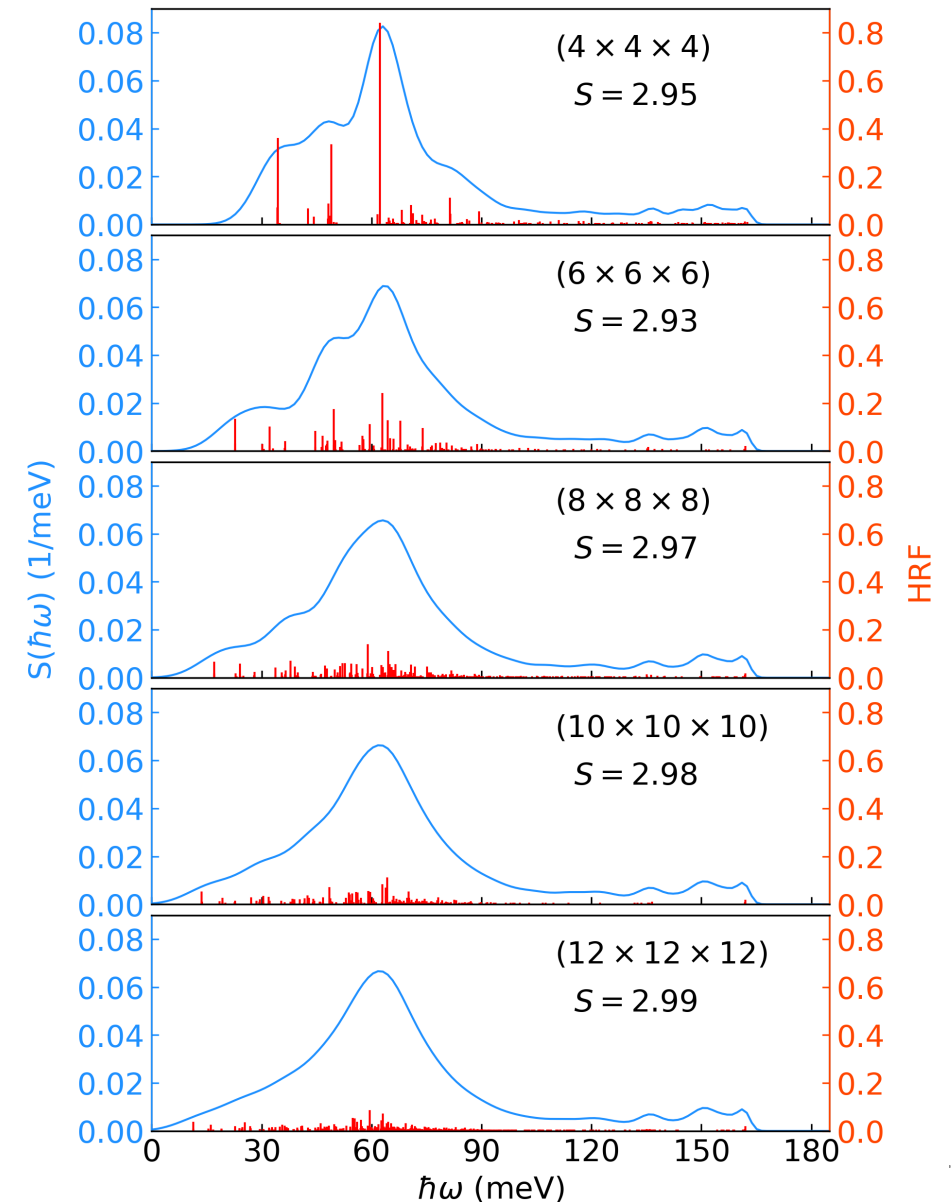
$$S = \sum_k S_k = \sum_k \frac{\omega_k \Delta Q_k^2}{2\hbar}$$

Spectral density of electron-phonon coupling

$$S(\hbar\omega) = \sum_k S_k \delta(\hbar\omega - \hbar\omega_k)$$

For NV<sup>-</sup> center in diamond, extrapolating to the dilute limit

- smooths the spectral density
- includes the contribution of **long-range phonons**



# Vibrational Modes Analysis

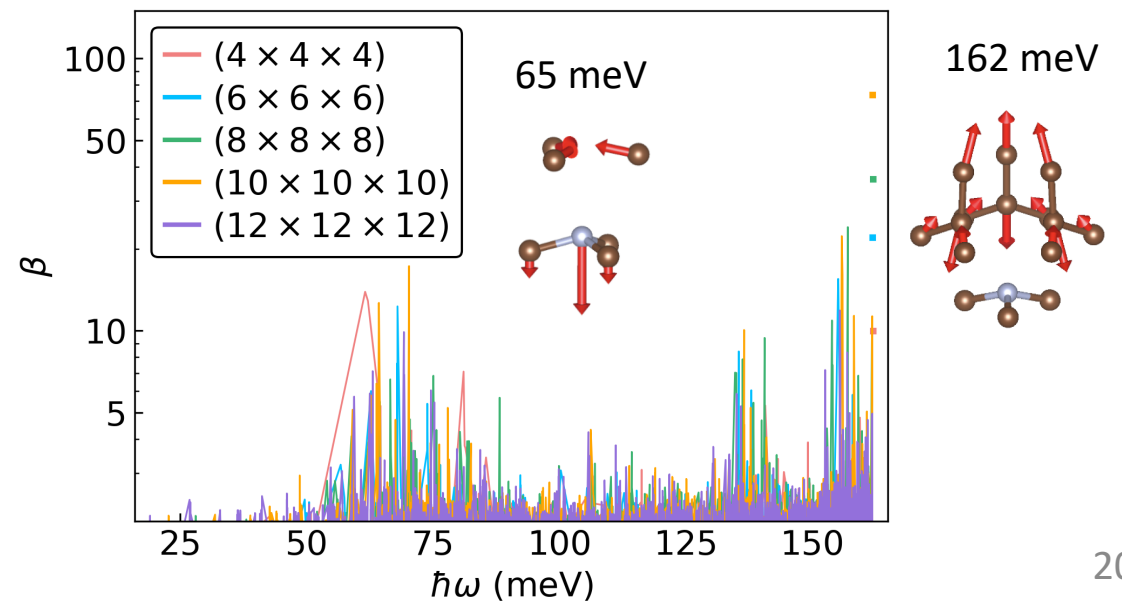
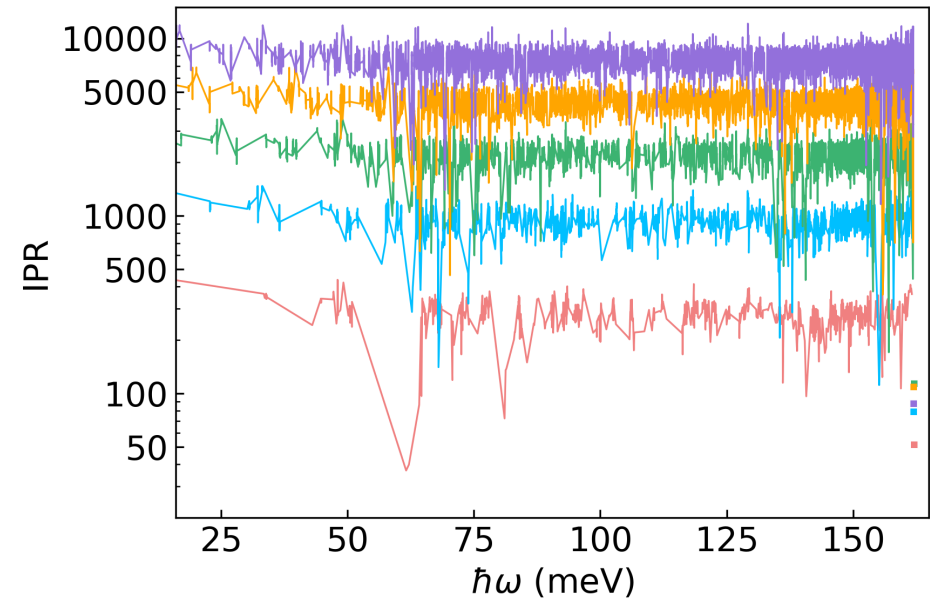
Inverse partition function (IPR)

$$\text{IPR}_k = \frac{1}{\sum_{\alpha=1}^N \left( \sum_{i=x,y,z} e_{k,\alpha i}^2 \right)^2}$$

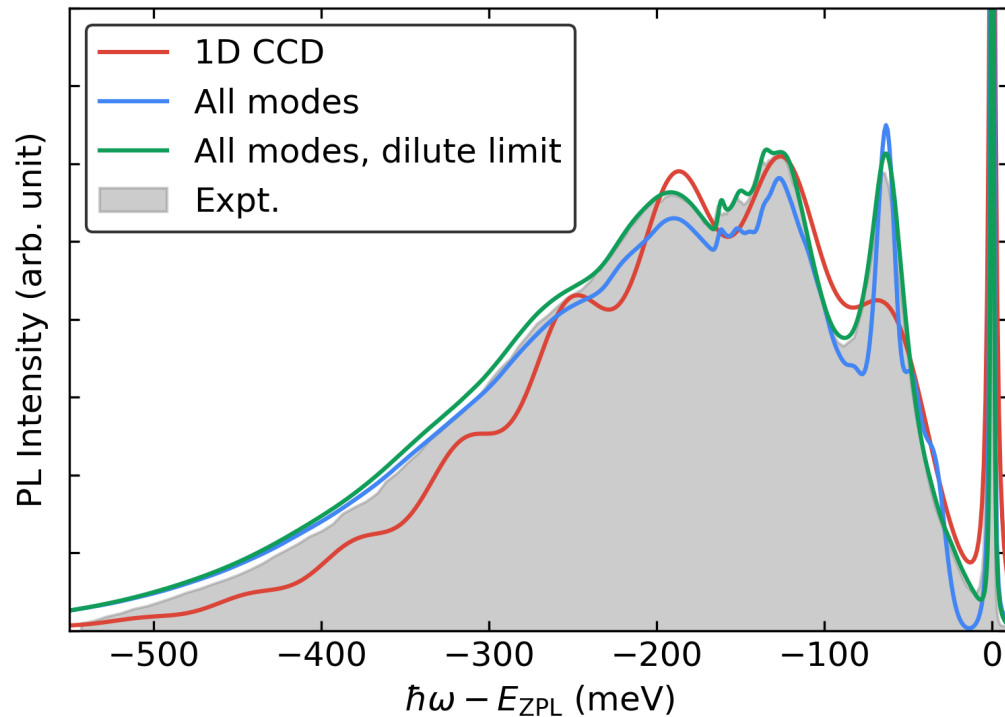
Localization factor ( $\beta$ )

$$\beta_k = \frac{N}{\text{IPR}_k}$$

- **Quasi-local vibrational modes** at 65 meV
- **Localized vibrational modes** at 162 meV



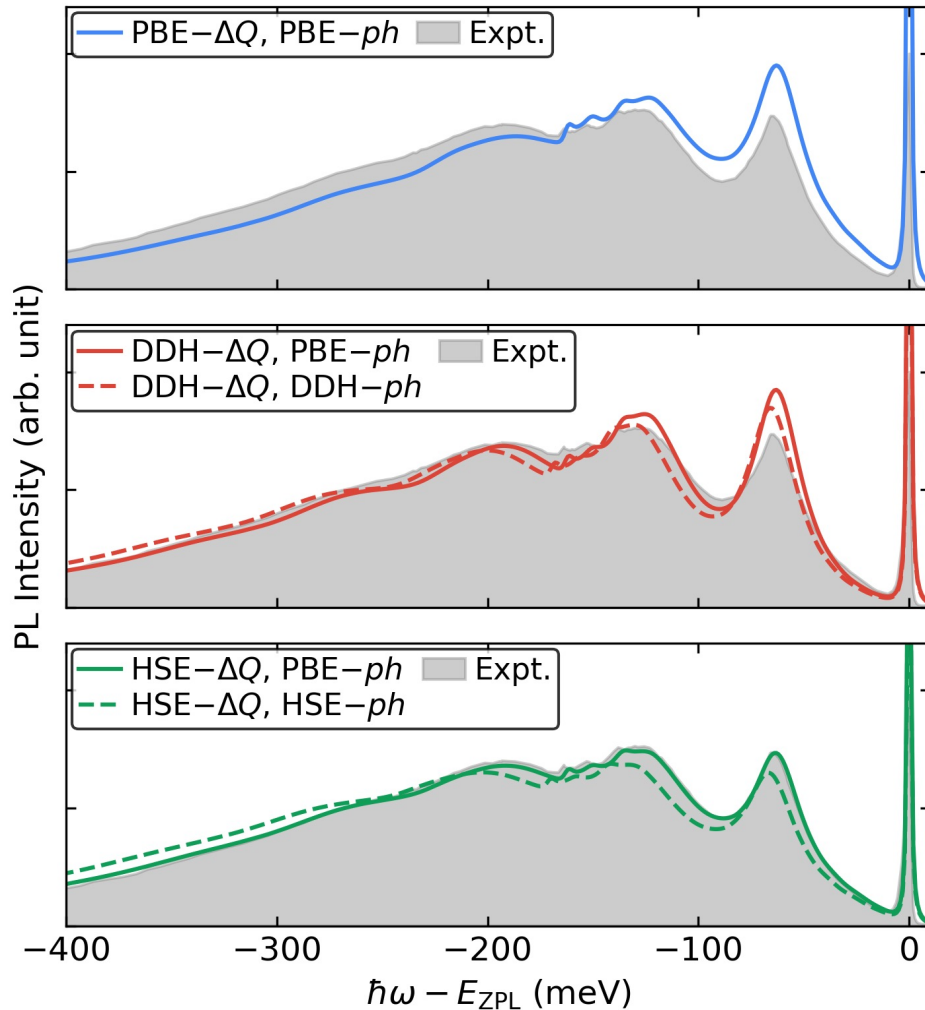
# PL Line Shape at the Dilute Limit



**The agreement between the theoretical and experimental PL line shapes is significantly improved by extrapolating to the dilute limit**

- Phonon side band dominates by the coupling with the 65 meV quasi-local vibrational mode
- Detailed features at  $\sim 125, 140, 155$  and  $165$  meV are correctly predicted
- Contributions of long-range phonons are included

# Comparison of Different Functionals



Debye-Waller factor:  $DWF \approx \exp(-S)$

	PBE- $\Delta Q$	DDH- $\Delta Q$	HSE- $\Delta Q$	Expt.
	PBE- $ph$	PBE- $ph$	PBE- $ph$	
		DDH- $ph$	HSE- $ph$	
DWF (%)	5.0	4.1	3.0	3.2

- Energies of **PBE** phonons are in the best agreement with the experiment
- **HSE** predicts the relative intensity the best
- **HSE- $\Delta Q$**  with **PBE- $ph$**  yields the line shape and the DWF in the best comparison with the experiment

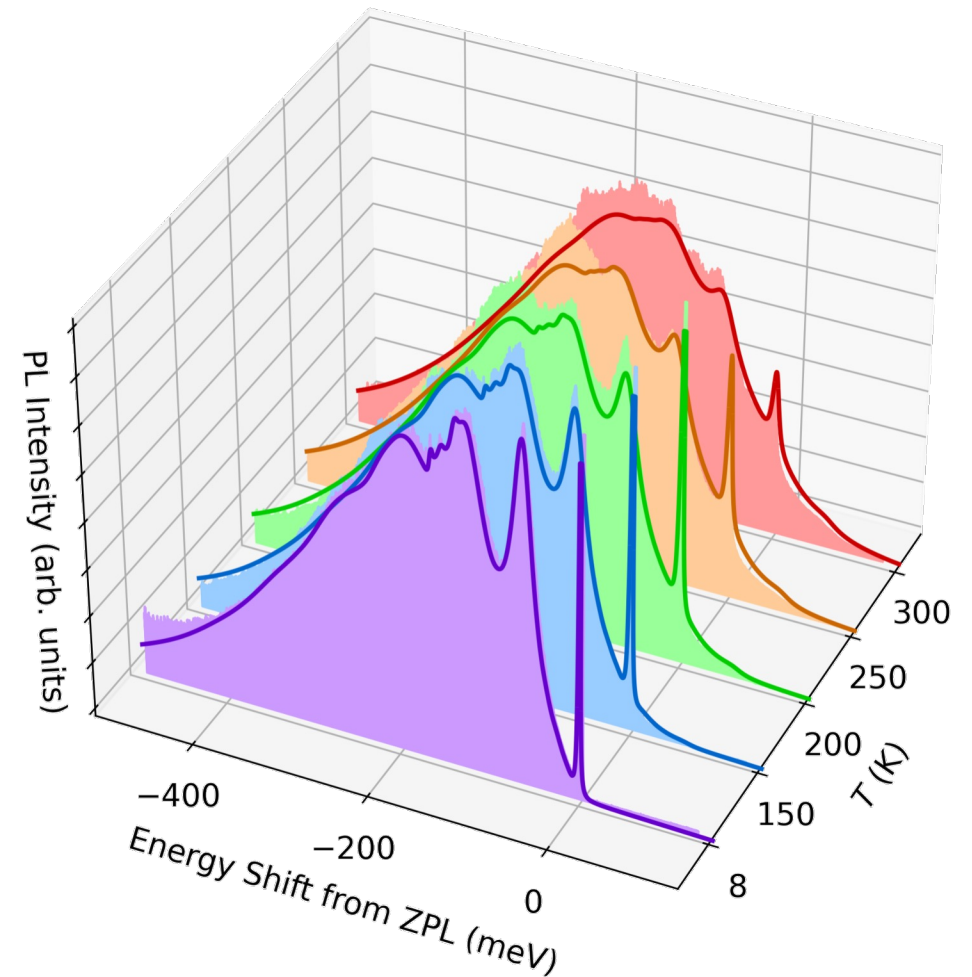
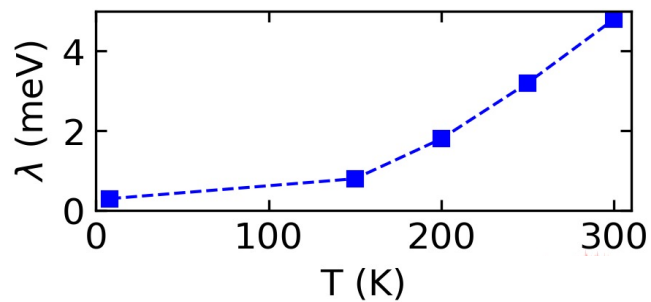
# Temperature Dependent PL

Temperature effect can be included through the **average occupations** of vibrational levels in the excited state

$$F(t, T) = \exp[S(t) - S(0) + C(t, T) + C(-t, T) - 2C(0, T)]$$

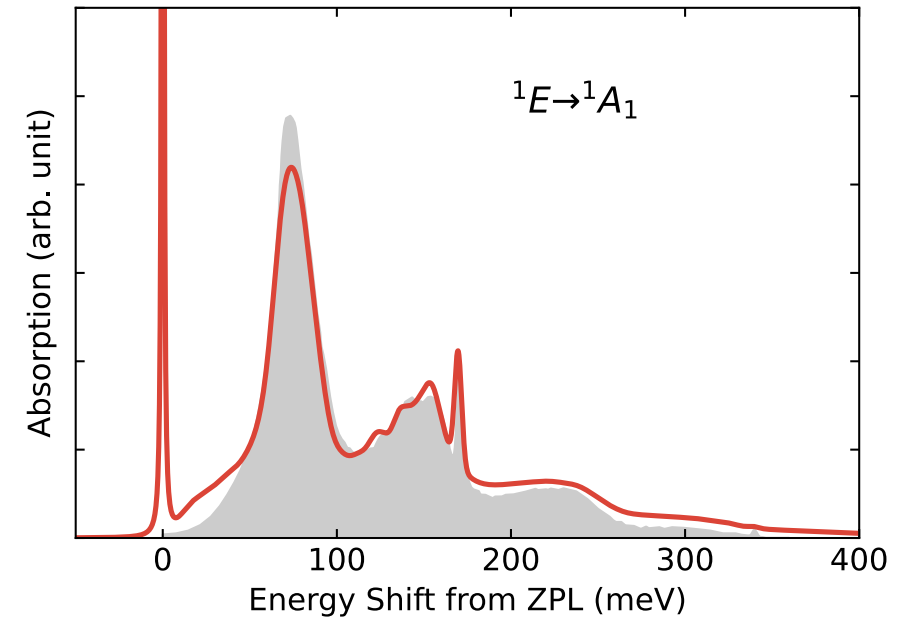
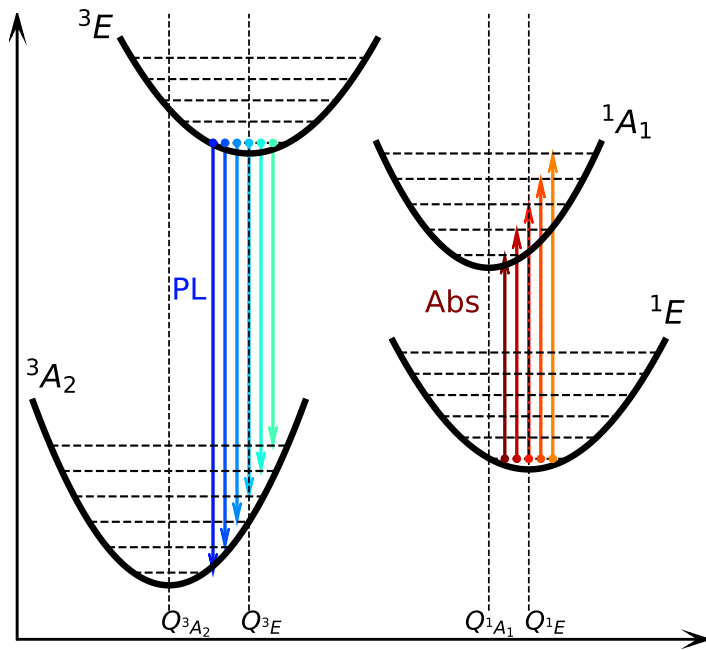
$$C(\hbar\omega, T) = \sum_k \bar{n}_k(T) S_k \delta(\hbar\omega - \hbar\omega_k)$$

ZPL broadening as a function of temperature





# Absorption between Singlet States



P. Kehayias et al., *Phys. Rev. B* **88**, 165202 (2013).

- Geometries and vibrational modes of the strongly-correlated  $^1A_1$  and  $^1E$  states are studied using **spin-flip TDDFT with analytical nuclear gradients** implemented in the WEST code



# Outline

---

- Theory and First-principles Methodology
- Photoluminescence of All Inorganic Perovskites
- Photoluminescence of Point Defects in Semiconductors
- **Summary and Outlook**

# Summary

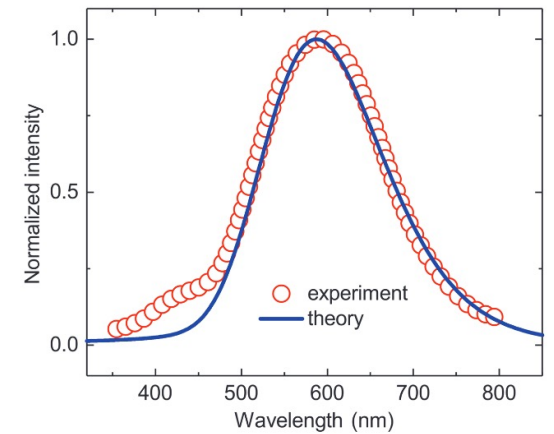
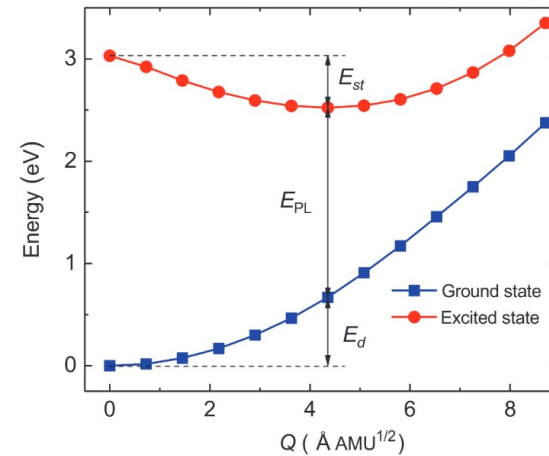
## PL spectra of solid-state systems can be characterized using first-principles approaches

### Light emitting all inorganic perovskites

- Formation of self trapped exciton (STE)
- **1D configuration coordinate diagram (CCD)**

J. Luo et al., *Nature* **563**, 541 (2018).

X. Wang et al., *J. Phys. Chem. Lett.* **10**, 501 (2019).

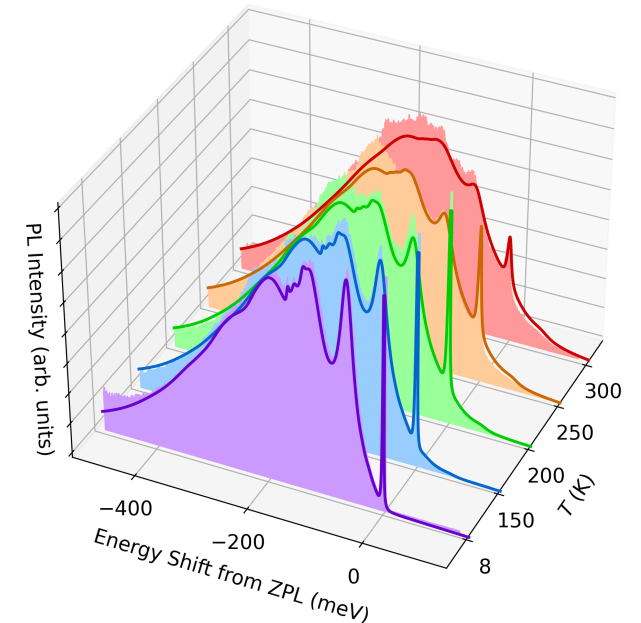


### Point defects in semiconductors

- Coupling between the optical transition and all vibrational modes
- **Generating function approach** for the line shape at finite temperature
- **Force constant matrix embedding approach** for finite-size effects

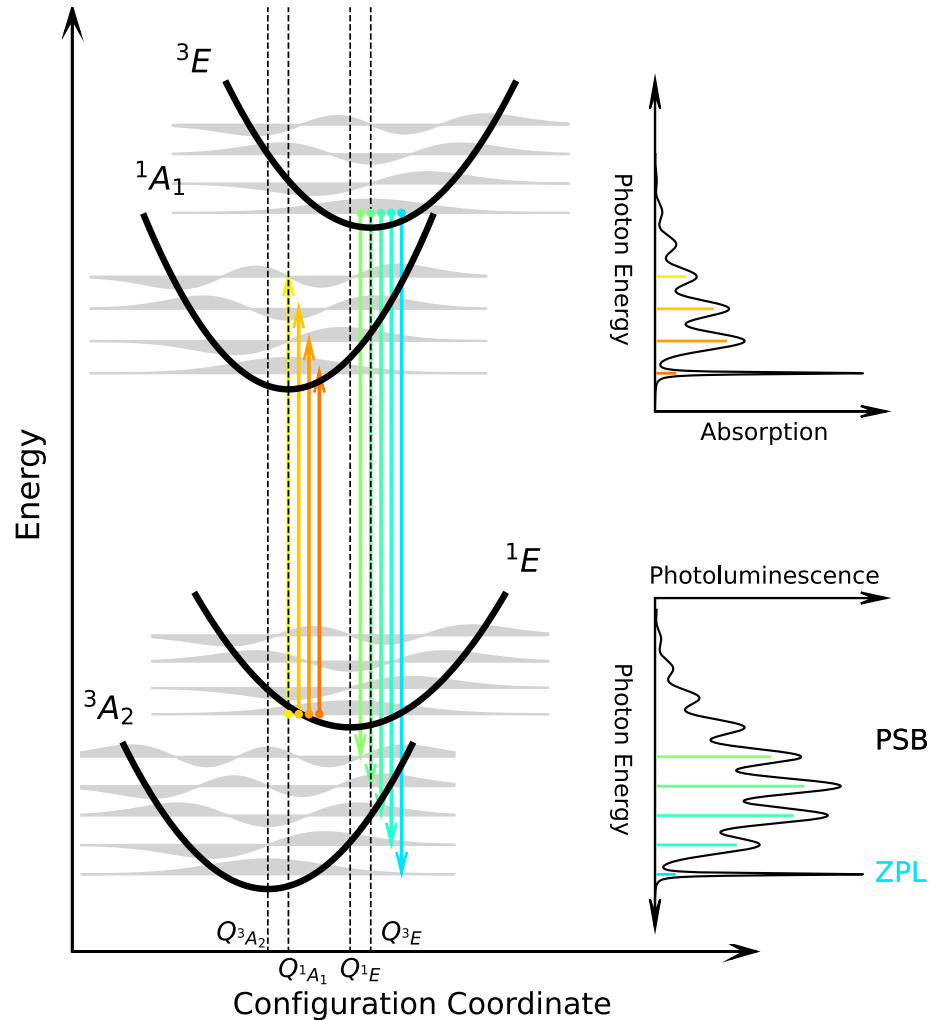
Y. Jin, M. Govoni et al., *Phys. Rev. Mater.* **5**, 084603 (2021).

Y. Jin, M. Govoni, and G. Galli, arXiv:2208.04504 (2022).



# Outlook

## Future work: method development for excited state potential energy surfaces



Methods based on DFT (CDFT, TDDFT)

- More rigorous treatment of excited states
- More accurate density functionals

Methods based on many-body perturbation theory (*GW*-BSE, QDET)

- Implementation of analytical nuclear forces

Quantum chemistry methods

- Implementation with periodic boundary condition
- Reducing the computational cost to enable calculations for large systems

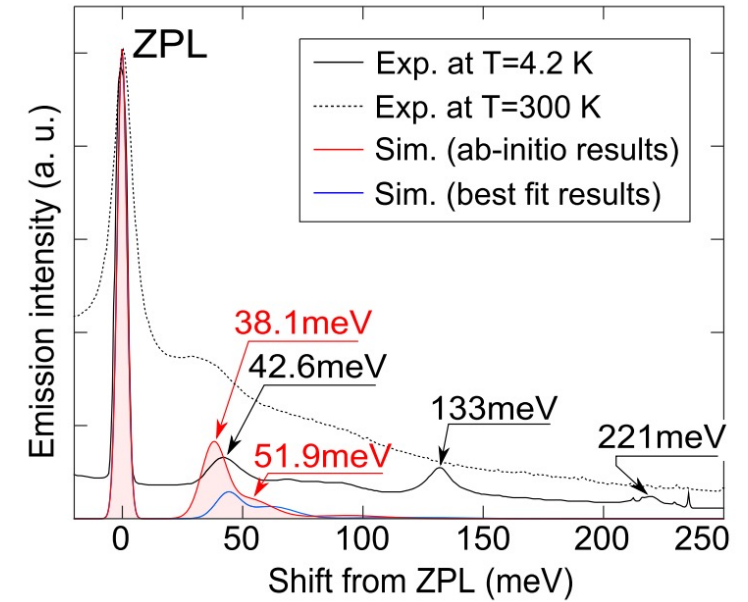
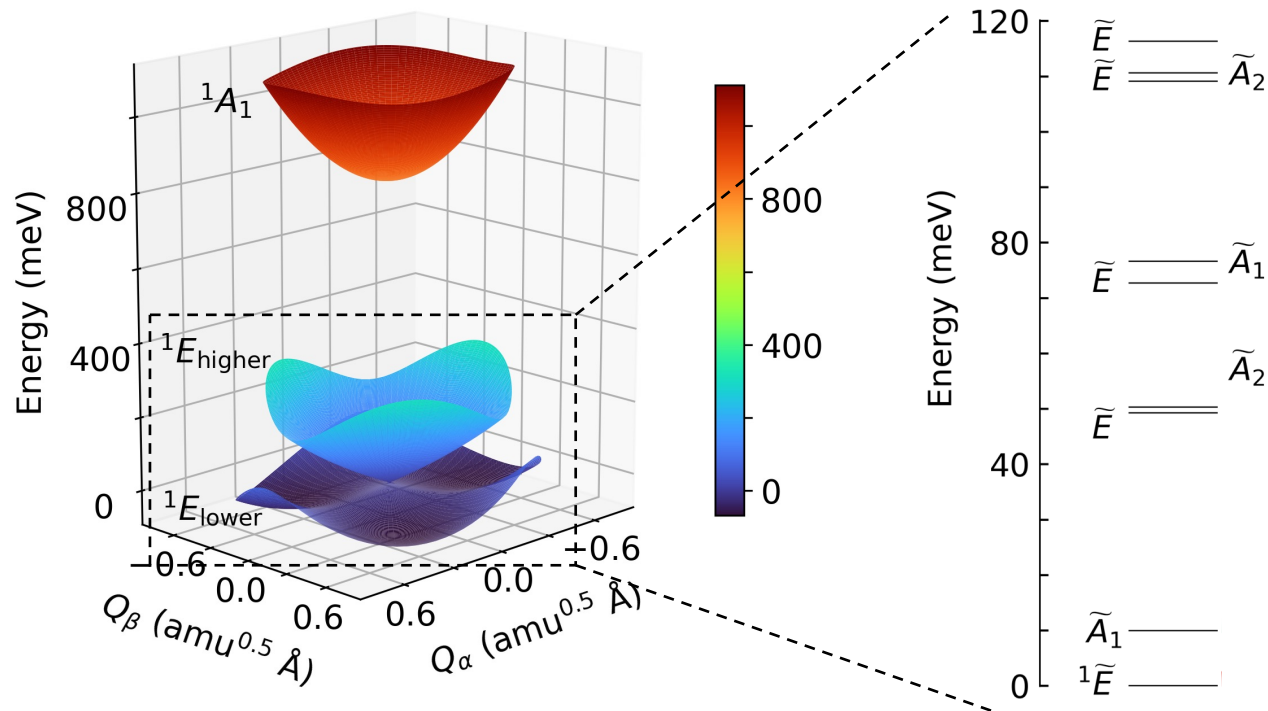
# Outlook

## Future work: beyond the approximations in the calculation of PL spectra

Non-Born-Oppenheimer effect and the anharmonicity

BO:  $|\Phi_m\rangle = |\Psi\rangle|X_m\rangle$

Non-BO:  $|\Phi_m\rangle = \sum_i (c_{mi}|\Psi_1\rangle|X_i\rangle + d_{mi}|\Psi_2\rangle|X_i\rangle)$



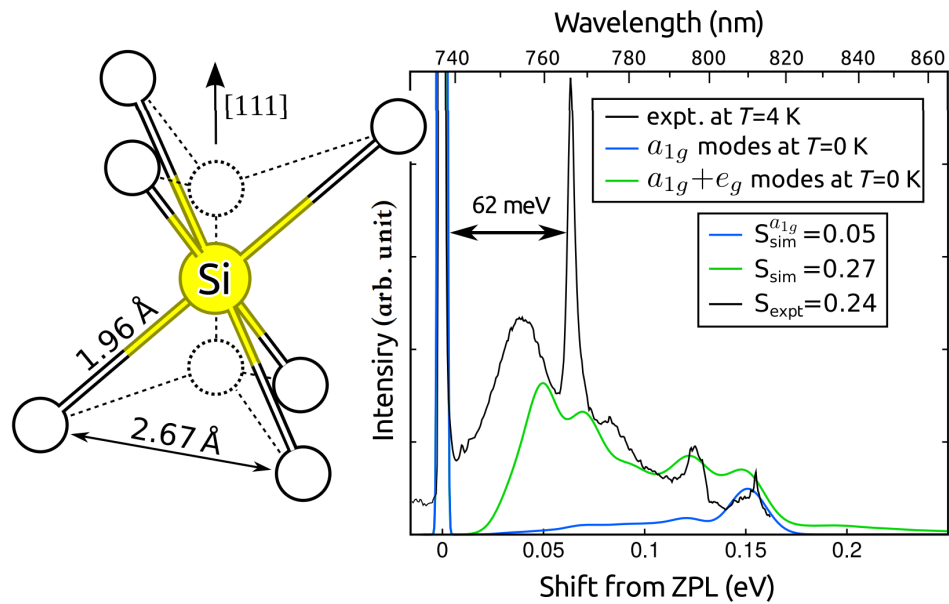
Y. Jin, M. Govoni, and G. Galli, arXiv:2208.04504.  
G. Thiering and A. Gali, *Phys. Rev. B* **98**, 085207 (2018).  
L. Razinkovas et al., *Phys. Rev. B* **104**, 045303 (2021).

# Outlook

## Future work: beyond the approximations in the calculation of PL spectra

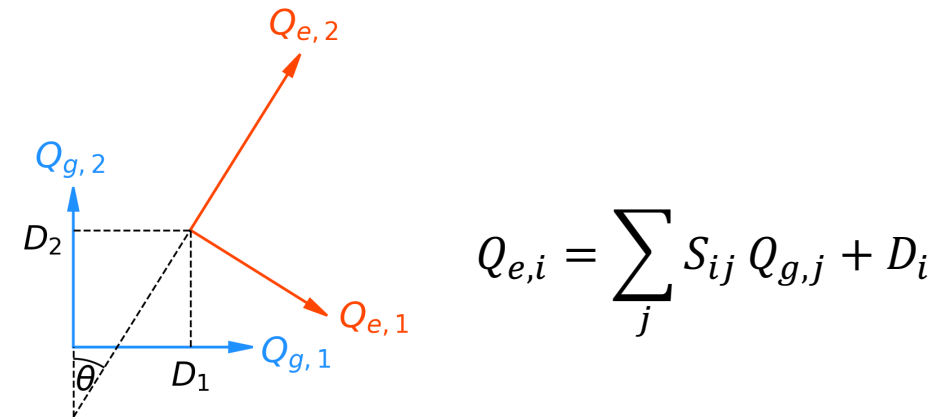
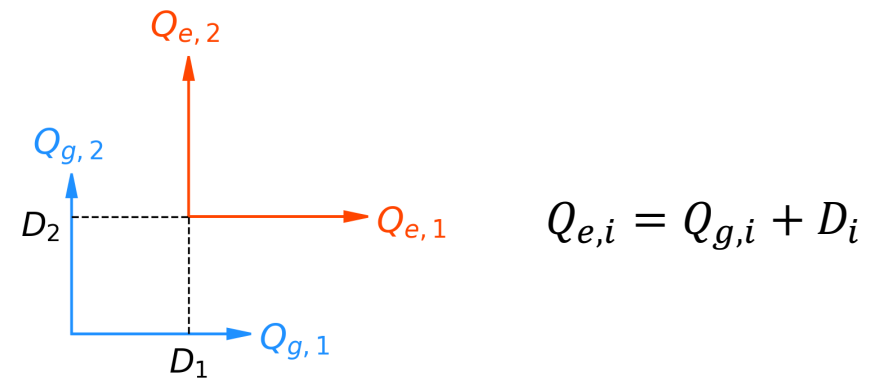
### Herzberg-Teller effect

$$\mu = \mu_0 + \sum_k \left( \frac{\partial \mu}{\partial Q_k} \right) \Delta Q_k$$



G. Thiering et al., *Phys. Rev. X* **8**, 021063 (2018).

### Duschinsky rotation effect



# Acknowledgement



Dr. Gary Wolfowicz  
Dr. Sean Sullivan  
Dr. F. Joseph Heremans



National Energy Research  
Scientific Computing Center

